## **Bipolar Junction Transistors**

## Peng Mei Department of Electronic Systems

Email: mei@es.aau.dk





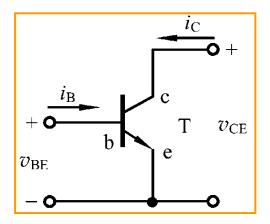
## **Learning objectives:**

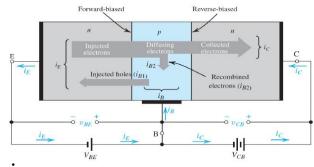
• Early effect

• Static operating point in power amplifier design



## $i_{\rm C} \sim v_{\rm CE}$ curve:



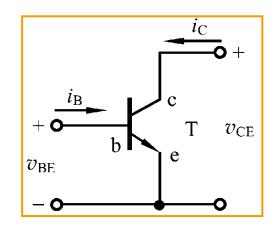


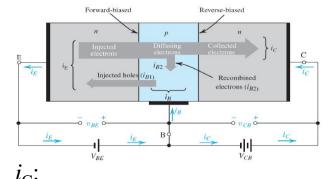
 $\iota_{\mathrm{C}}$ :

Electrons  $E \longrightarrow B \longrightarrow C$ 

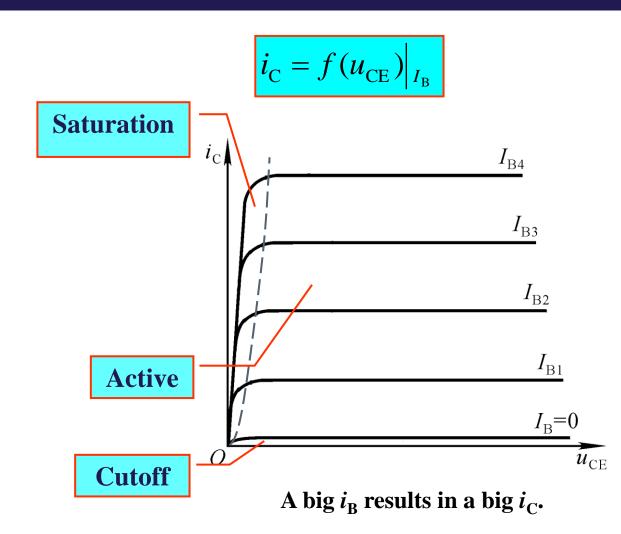


#### $i_{\rm C} \sim v_{\rm CE}$ curve:





Electrons  $E \longrightarrow B \longrightarrow C$ 





Mode	EBJ	CBJ
Cutoff	Reverse	Reverse
Active	Forward	Reverse
Saturation	Forward	Forward

Saturation region:  $i_c$  is mainly controlled by  $v_{ce}$ ,  $\beta i_b > i_c$ 

$$V_{BE} = 0.7V, V_{CE} < 1V$$

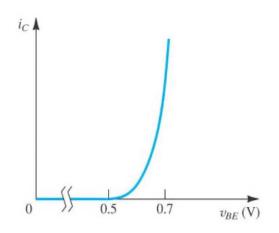
Active region:  $i_c$  is basically parallel with  $v_{ce}$ ,  $\beta i_b = i_c$ 

$$V_{BE} = 0.7V, V_{CE} > 1V$$

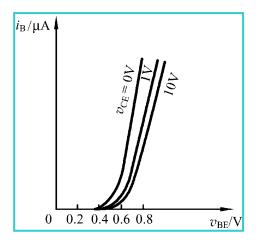
Cutoff region:  $i_c$  is approaching to 0,  $i_b \approx i_c \approx 0$ 

$$V_{BE} < 0.5V$$

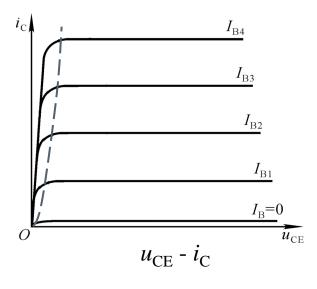




$$u_{
m BE}$$
 -  $i_{
m C}$ 

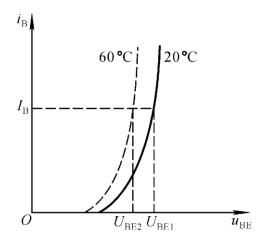


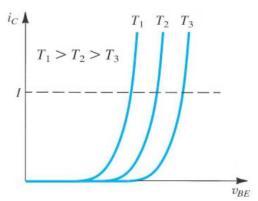
 $u_{
m BE}$  -  $i_{
m B}$ 

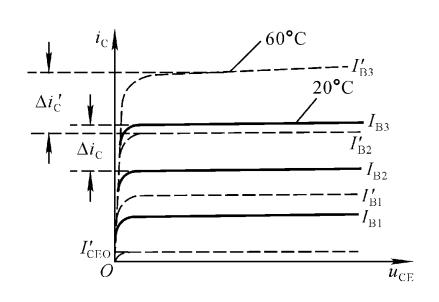




### Effects of temperature:

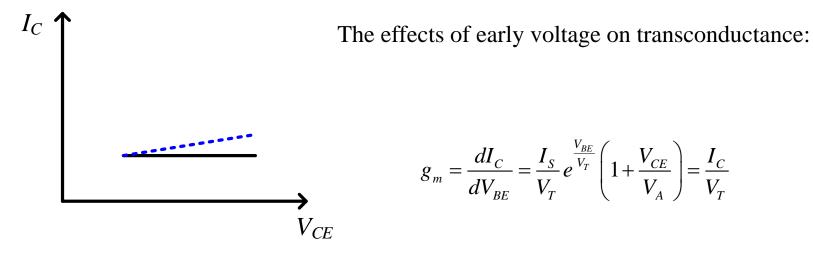








#### Early effects:



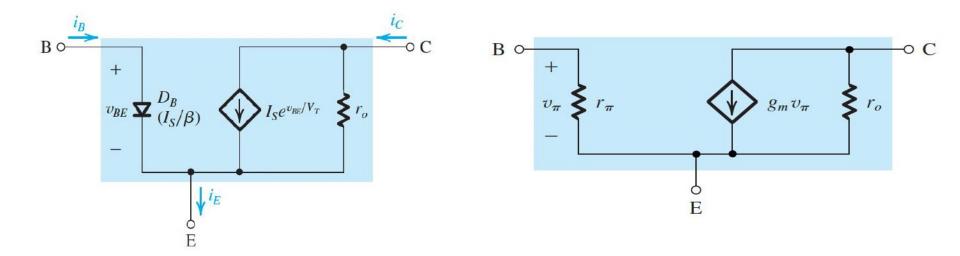
$$g_{m} = \frac{dI_{C}}{dV_{BE}} = \frac{I_{S}}{V_{T}} e^{\frac{V_{BE}}{V_{T}}} \left( 1 + \frac{V_{CE}}{V_{A}} \right) = \frac{I_{C}}{V_{T}}$$

Not change

$$I_C = I_S e^{\frac{V_{BE}}{V_T}} \left( 1 + \frac{V_{CE}}{V_A} \right)$$
 V<sub>A</sub> is early voltage



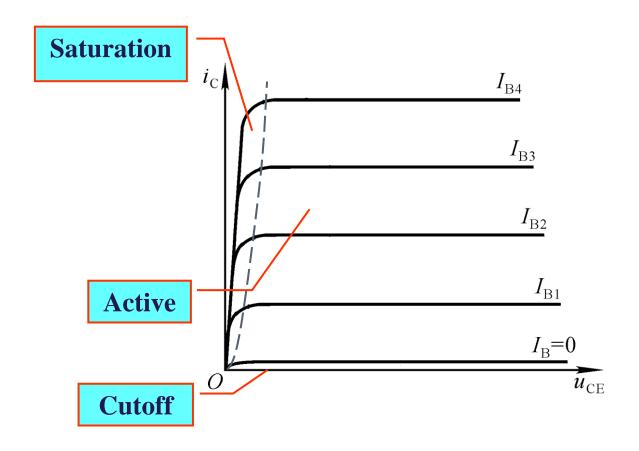
Inclusion of early effect in large-signal and small-signal models:



$$r_o = \frac{V_A}{I_S e^{\frac{V_{BE}}{V_T}}} \approx \frac{V_A}{I_C}$$

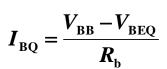


## Power amplifier:





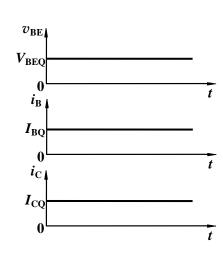
## DC biasing (Static operating point (Q point)):

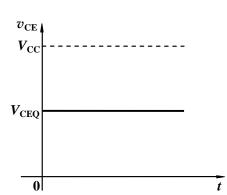


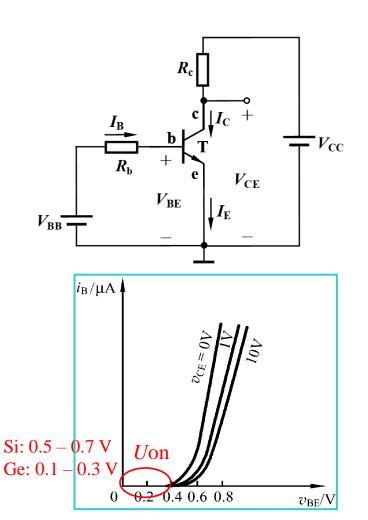
$$I_{CQ} \approx \beta \cdot I_{BQ}$$

$$V_{\text{CEQ}} = V_{\text{CC}} - I_{\text{CQ}} R_{\text{c}}$$

 $Q(I_{BQ}, I_{CQ}, V_{CEQ})$ 

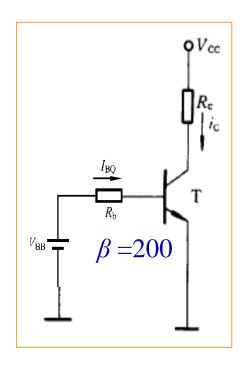








#### Calculate Q point:

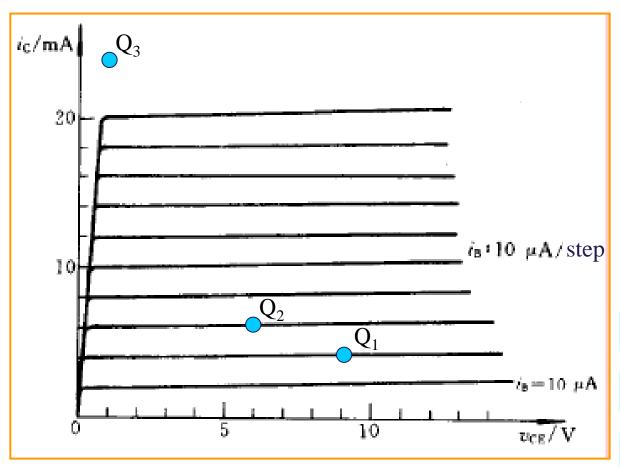


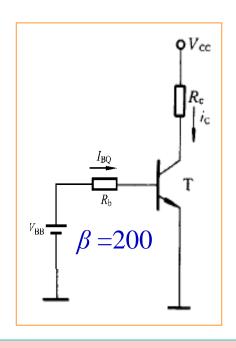
$$V_{\text{CC}} = 15 \text{V}, R_{\text{C}} = 1.5 \text{k}\Omega, i_{\text{B}} = 20 \mu \text{A}$$
  
Q(20\mu A, 4m A, 9 V)

$$V_{\text{CC}}$$
=12V,  $R_{\text{C}}$ =1k $\Omega$ ,  $V_{\text{BB}}$ =2.2V,  $R_{\text{b}}$ =50k $\Omega$ ,  $V_{\text{BEQ}}$ =0.7V Q(30 $\mu$ A, 6m A, 6V)

$$V_{\text{CC}}$$
=6V,  $R_{\text{C}}$ =200 $\Omega$ ,  $V_{\text{BB}}$ =3.2V,  $R_{\text{b}}$ =20k $\Omega$ ,  $V_{\text{BEQ}}$ =0.7V 
$$Q(125\mu\text{A}, 25\,\text{m A}, 1\,\text{V})$$







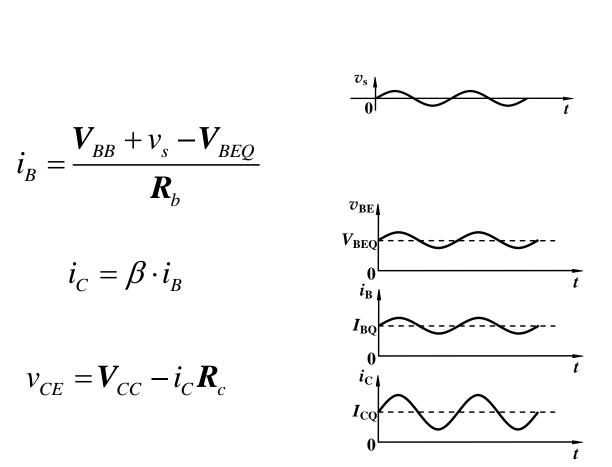
 $Q_1(20\mu A, 4m A, 9V)$ 

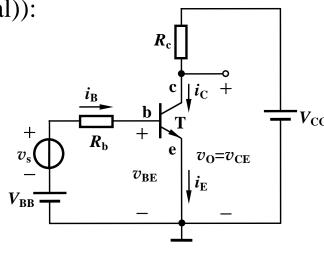
 $Q_2(30\mu A,6m A,6V)$ 

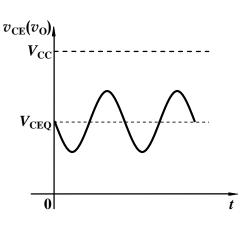
 $Q_3(125\mu A, 25 \text{ m A}, 1 \text{ V})$ 



With a perturbation (a sinusoidal signal (alternating signal)):

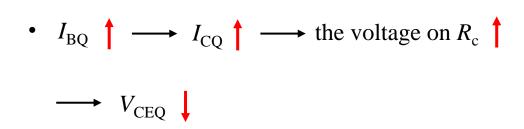




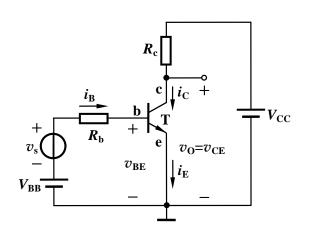


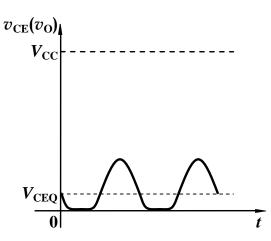


The effects of static operating point on output voltage



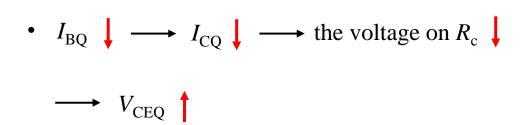






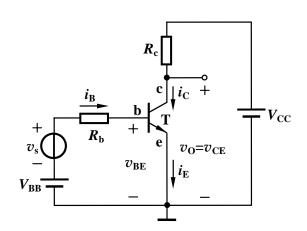


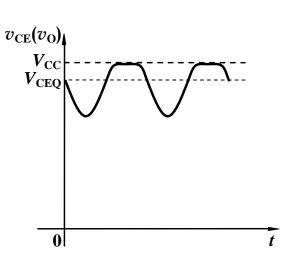
The effects of static operating point on amplification



A proper static operating point should be provided to make the transistor operate at the active mode (amplification region).

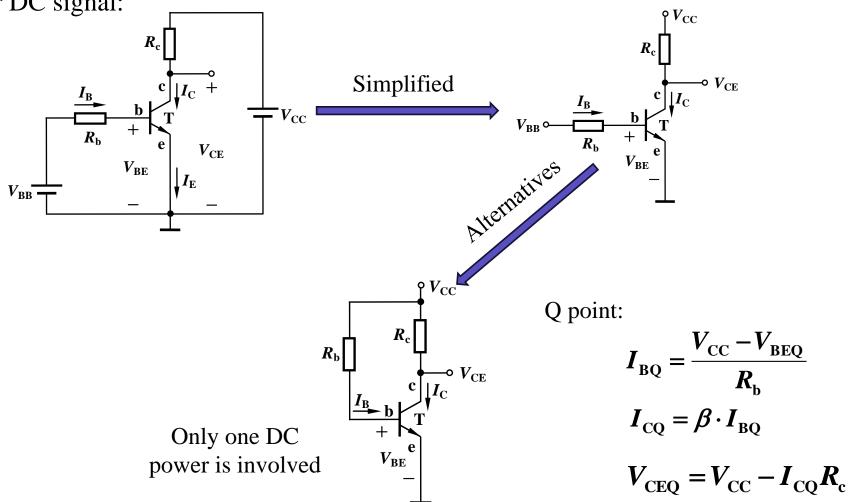
The amplitude of output signal is limited by  $V_{\rm CC}$ .





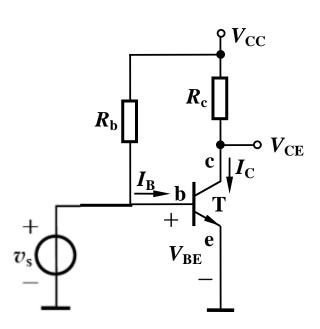








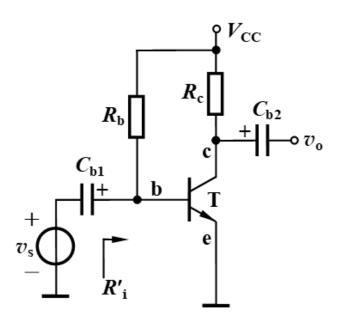
## When AC signal is added directly:



What will happen when  $v_s = 0$ ?



#### When AC signal is added with capacitors:



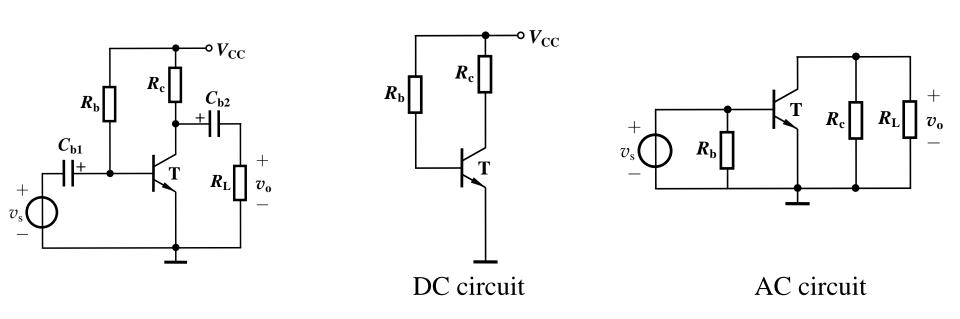
Two capacitors are added at input and output ends to isolate DC and AC signals.

The involvements of  $v_s$  and  $v_o$  do not affect the Q point of the circuit.

The frequency of  $v_s$  can not be too small.



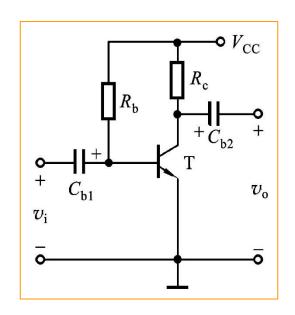
DC circuit and AC circuit:



DC circuit: capacitor is open, AC source is open;

AC circuit: capacitor is short, DC source is short;





$$\beta=80,$$
  $R_{\rm b}=300{\rm k}\Omega$  ,  $R_{\rm c}=2{\rm k}\Omega$  ,  $V_{\rm CC}=+12{\rm V}$   $V_{\rm BEO}$  is assumed to be 0

Calculate Q point, which region does the BJT operate?

 $Q(40\mu A, 3.2mA, 5.6V)$  Active region

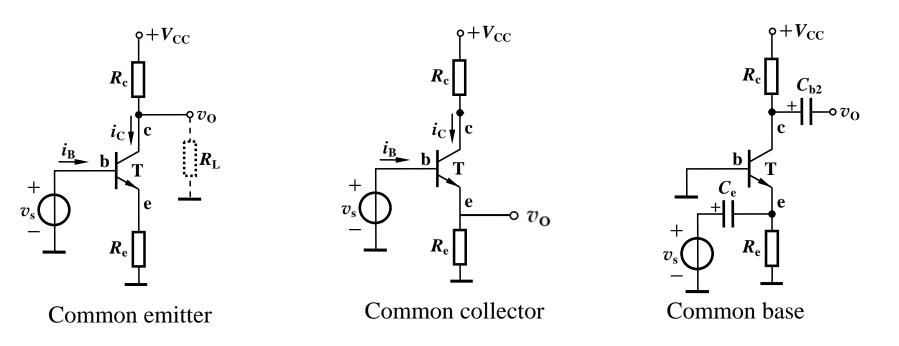
If  $R_b=100$ k $\Omega$ ,

 $Q(120\mu A, 6.0mA, 0V)$  Saturation region

If  $R_b = 300 \text{k}\Omega$ ,  $R_c = 5 \text{k}\Omega$ 

 $Q(40\mu A, 2.4mA, 0V)$  Saturation region





Common emitter: signal is input from the base, and output from the collector;

Common collector: signal is input from the base, and output from the emitter;

Common base: signal is input from the emitter, and output from the collector;



# **Thanks**